



FFPF60SA60DS 8 A, 600 V, STEALTH™ Dual Series Diode

Features

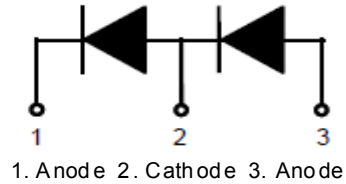
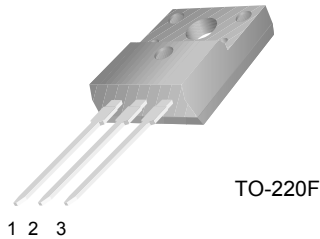
- Stealth Recovery $t_{rr} = 39 \text{ ns}$ (@ $I_F = 8 \text{ A}$)
- Max Forward Voltage, $V_F = 2.4 \text{ V}$ (@ $T_C = 25^\circ\text{C}$)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

Applications

- SMPS FWD, Motor Drive FWD, Snubber Diode
- Hard Switched PFC Boost Diode
- UPS FWD

Description

The FFPF60SA60DS is STEALTH™ dual series diode with soft recovery characteristics. It is silicon nitride passivated ionimplanted epitaxial planar construction. This device is intended for use as freewheeling of boost diode in switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Rating	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V_R	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 95^\circ\text{C}$	8	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	80	A
P_D	Power Dissipation	26	W
W_{AVL}	Avalanche Energy (1 A, 40 mH)	20	mJ
T_J, T_{STG}	Operating Junction and Storage Temperature	-65 to +175	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Max.	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.125	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	62.5	$^\circ\text{C}/\text{W}$

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF60SA60DSTU	FFPF60SA60DS	TO-220F	Tube	N/A	N/A	30

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Min.	Typ.	Max.	Unit	
V_{F1}	Forward Voltage $I_F = 8\text{ A}$ $I_F = 8\text{ A}$	$T_C = 25^\circ\text{C}$	-	2.0	2.4	V
		$T_C = 125^\circ\text{C}$	-	1.6	2.0	
I_{R1}	Reverse Current @rated V_R	$T_C = 25^\circ\text{C}$	-	-	100	μA
		$T_C = 125^\circ\text{C}$	-	-	1000	
t_{rr}	Maximum Reverse Recovery Time ($I_F = 1\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$)	-	-	25	ns	
t_{rr}	Maximum Reverse Recovery Time ($I_F = 8\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$)	-	-	30	ns	
t_{rr}	Reverse Recovery Time	-	39	-	ns	
I_{rr}	Reverse Recovery Current Reverse	-	2	-	A	
Q_{rr}	Recovery Charge ($I_F = 8\text{ A}$, $di_F/dt = 200\text{ A}/\mu\text{s}$, $V_R = 390\text{ V}$)	-	39	-	nC	

Notes:
1: Pulse: Test Pulse width = 300 μs , Duty Cycle = 2%

Test Circuit and Waveforms

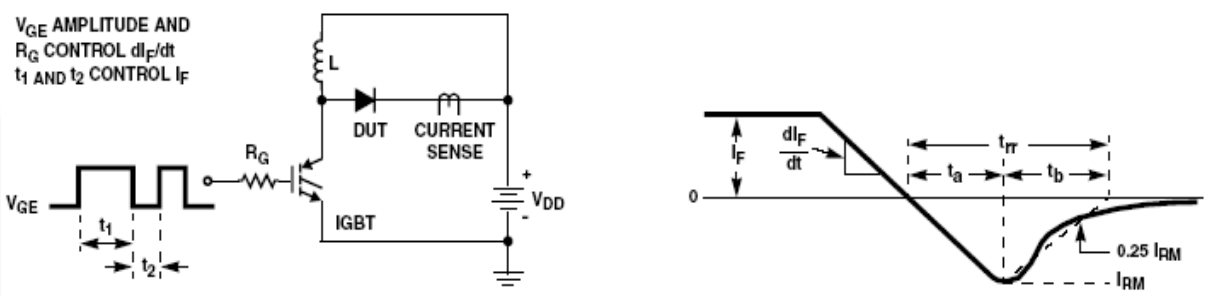


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

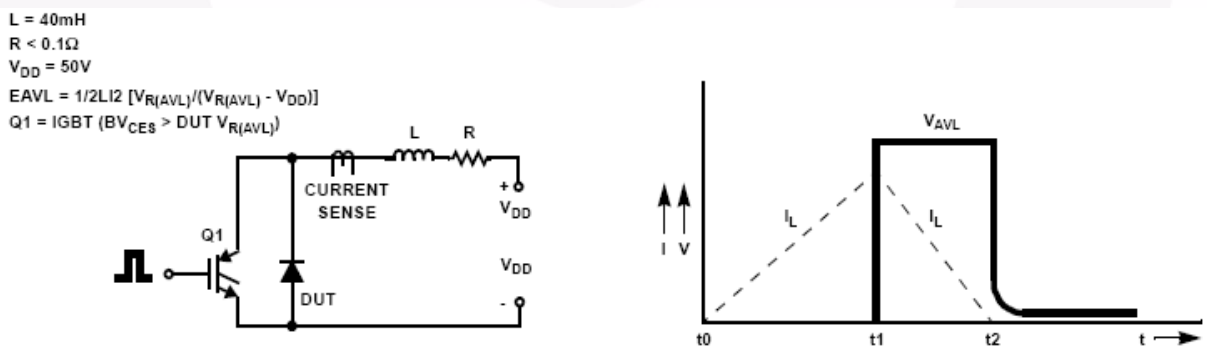


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

$L = 40\text{mH}$
 $R < 0.1\Omega$
 $V_{DD} = 50\text{V}$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
 $Q1 = \text{IGBT } (BV_{CES} > \text{DUT } V_{R(AVL)})$

Typical Performance Characteristics

Figure 3. Typical Forward Voltage Drop vs. Forward Current

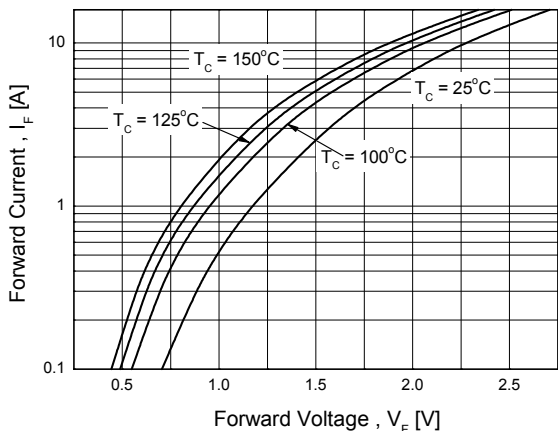


Figure 4. Typical Reverse Current vs. Reverse Voltage

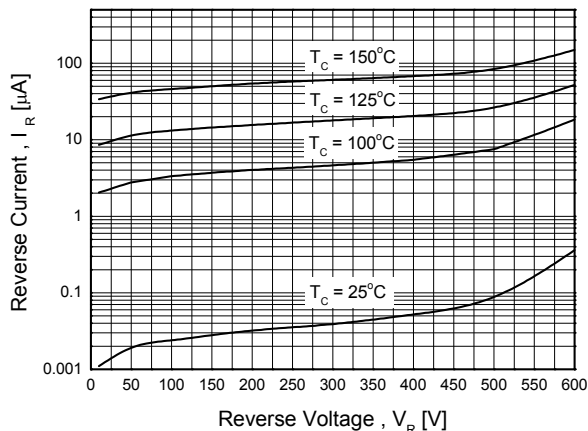


Figure 5. Typical Junction Capacitance

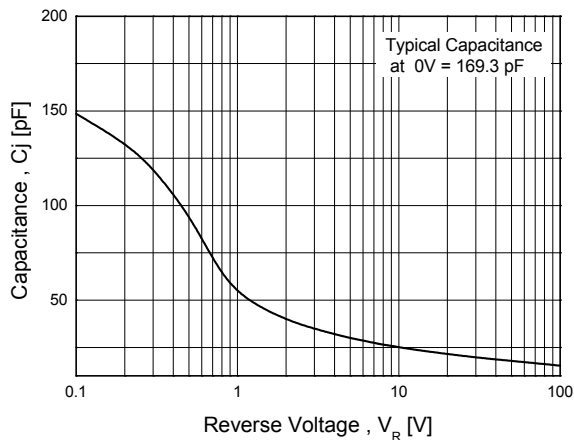


Figure 6. Typical Reverse Recovery Time vs. di_F/dt

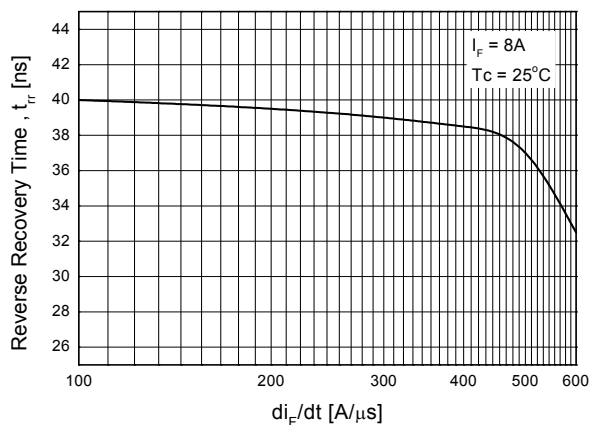


Figure 7. Typical Reverse Recovery Current vs. di_F/dt

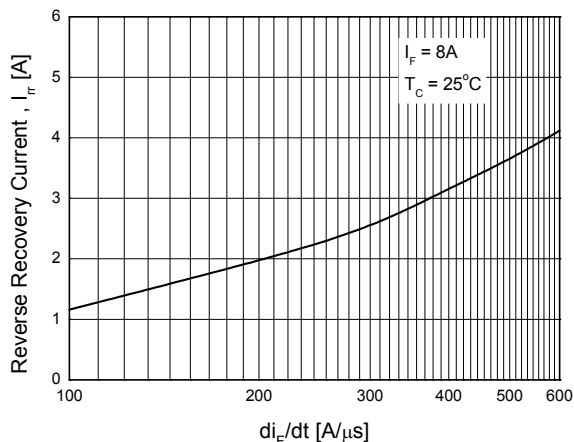
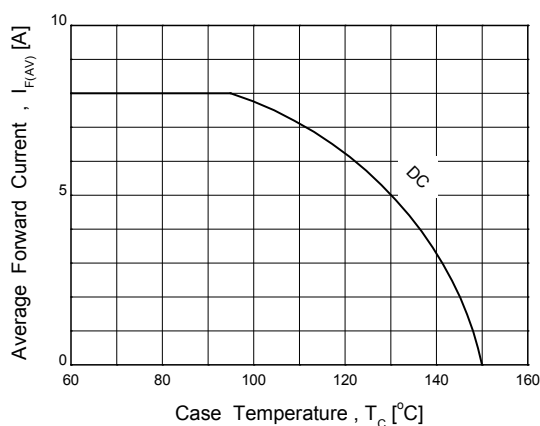


Figure 8. Forward Current Derating Curve



Package Dimensions

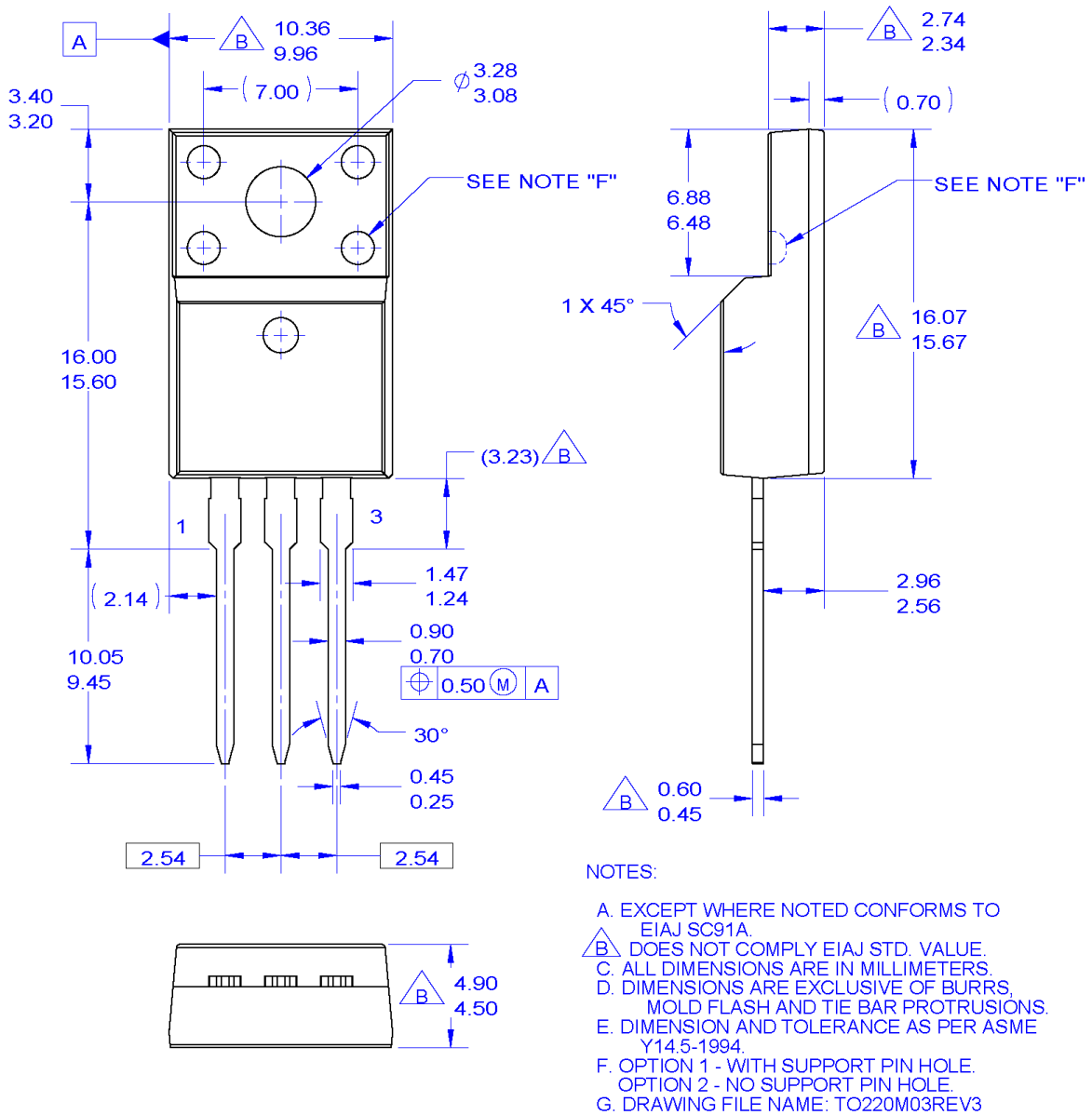


Figure 9. TO-220F 3L - TO220, MOLDED, 3LD, FULL PACK, EIAJ SC91, STRAIGHT LEAD

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